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2012

ONS00187
09/917,731

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: Imam et al.
Serial No.: 09/917,731
Filing Date: July 31, 2001
Group Art Unit: 2812
Examiner: Roman, Angel
Title: **METHOD FOR MANUFACTURING A HIGH
VOLTAGE MOSFET SEMICONDUCTOR
DEVICE WITH ENHANCED CHARGE
CONTROLLABILITY**

I HEREBY CERTIFY THAT THIS CORRESPONDENCE IS BEING DEPOSITED
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SEMICONDUCTOR COMPONENTS INDUSTRIES, LLC

Name of Assignee

Lydia McChamara 10/8/03
SIGNATURE DATE

AMENDMENT

SIR:

In response to the office action mailed July 14, 2003,
please amend the above-identified application as follows.